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A needle-like Cu₂CdSnS₄ alloy nanostructure-based integrated electrochemical biosensor for detecting the DNA of Dengue serotype 2

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Abstract The authors describe an integrated biosensor for amperometric DNA detection of Dengue virus in real time. Cu_2CdSnS_4 (CCTS) quaternary alloy nanostructures were successfully synthesized, deposited on an oxygen-etched silicon substrate (O₂/Si) via spin coating, and annealed at 400 °C. The nanostructures were investigated by using UV-vis spectroscopy, X-ray diffraction, atomic force microscopy and scanning electron microscopy. Interdigitated electrodes were fabricated using silver as a metal contact deposited on the CCTS/O₂/Si substrate using a thermal evaporator vacuum coater and a hard mask. The quaternary alloy acts as a support

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for immobilization of a Dengue-specific DNA probe that is employed as the recognition element. Single-stranded DNA in concentrations from 100 f. to 10 nM were successfully recognized via amperometry, typically at a working voltage of 1.5 V. The lower detection limit is 17 nM. Sensitivity is found to be 24.2 μ A nM⁻¹ cm⁻². The biosensor is inexpensive, fast, highly sensitive, and has low power consumption.

Keywords Impedance · Capacitance · Sensitivity · Interdigitated electrodes · Nanostructures · Band gap · Immobilization · DNA probe · Concentrations · Electrical properties

Introduction

Dengue virus belongs to the *Flaviviridae* family comprising 5 serotypes (DENV-1 through DENV-5). The disease is transmitted by *Aedes aegypti* mosquito which feeds on human blood. Dengue virus has a spherical nucleocapsid with approximate size of 50–60 nm. The virus contains a single-stranded RNA of 11,000 nucleotides in length [1].

Due to the limited sensitivity of existing methods, there is a need to detect the disease in early stages; one way of accomplishing that is to use biosensors. Advances in nanotechnology have motivated researchers to develop biosensors in different areas including medicine and biomolecular detection of DNA [2], bacteria [3], RNA [4], protein [5], enzyme [6], glucose [7] and pH sensing [8]. DNA biosensors usually rely on the immobilization of a single-stranded DNA (ssDNA) probe onto a surface, which permits it to bind its complementary DNA target sequence by hybridization [9]. The method of transduction depends on the type of physicochemical change resulting from the sensing event whereas transduction of hybridization can be measured optically [10], electrochemically

[11], or mass-sensitive [12]. DNA can be immobilized on surfaces using different methods; physical adsorption, covalent immobilization and streptavidin-biotin. 1-Ethyl-3-(3dimethylaminopropyl) carbodiimide (EDC) converts the carboxyl group into O-acylisourea intermediate that reacts with the amine group resulting in a covalent bonding between biomolecules and the solid surface. Moreover, aminated-DNA probes can be immobilized on the carboxylate-terminated 4-aminobenzoic acid using EDC and N-hydroxy

sulfosuccinimide (NHS) [13]. Many biosensors require attaching a label to the target for easy detection; these labels can be magnetic beads, fluorophores or active enzymes [14]. Researchers are actively pursuing new methods to design and fabricate biosensors based on interdigitated elec-

sign and fabricate biosensors based on interdigitated electrodes (IDEs), which are the most common sensing capacitive structure since they are more favored and highly effective in acquiring effective dielectric properties [15]. IDEs are usually considered as the major part for sensing operation, where electrical signals generated by the sensing material have to be detected by IDEs [16]. The fabrication process of IDEs by photolithography was dominant in the near past and consists of different steps including photoresist coating, exposure and etching. This process requires the use of special equipment [17] thus, alternative approaches were attempted utilizing techniques such as screen printing [18], inkjet-printing [19], microfabrication [20] and stamp method [21]. These techniques are widely used in many sensing applications in bacteria [22], gas [23], pressure [24] and humidity [25].

At the DNA level, there is a need for nanostructures that can bind DNA probe strands and act as a recognition element in the sensing device. The I₂-II-IV-VI₄ (I = Cu,Ag; II = Zn,Cd; I = Si,Ge,Sn; VI = S,Se) series of quaternary alloys have attracted significant interest due to their appropriate energy band gaps (E_g); 1.1–1.5 eV, high optical absorption coefficient; 10^4 - 10^5 cm⁻¹ and high abundant elements. Cu₂CdSnS₄ (CCTS) alloy nanostructures have been synthesized using solvothermal method [26], pulsed laser deposition [27], microwave irradiation method [28], spray pyrolysis deposition [29], co-sputtering deposition [30] and facile synthesis [31]. Using ultrasonic cleaning in synthesizing CCTS quaternary alloy nanostructures, via spin coating technique, introduces more peaks, where the crystallite size increases under high annealing temperature [32].

Herein, CCTS alloy nanostructures were synthesized and then deposited, using spin coating, on O_2/Si at annealing temperature; 400 °C. The optical, structural, morphological and topographical properties of the alloy were investigated thoroughly. The design and fabrication of Ag interdigitated electrodes is described in details, and its morphological properties were characterized. The electrical properties of the DNA probe and different concentrations of Dengue DNA serotype-2 were identified.

Experimental

Synthesis of CCTS solution

All chemicals and solvents were purchased from Sigma-Aldrich (USA, http://www.sigmaaldrich.com); the precursor solutions of CCTS alloy nanostructures were prepared from copper (II) chloride dihydrate (0.6 M), cadmium (II) chloride dihydrate (0.8 M), tin (II) chloride dihydrate (0.8 M), thiourea (0.8 M), 2-methoxyethanol and monoethanolamine. The solvent and stabilizer were 2-methoxyethanol and monoethanolamine, respectively. The molar ratios of Cu, Cd, Sn and S in the solution were 2:1:1:4.

The precursors were mixed using a magnetic stirrer for 3 h (1500 RPM) at 50 °C to dissolve the metals completely, which forms a yellow and transparent solution. Moreover, the solution has been covered with parafilm and placed inside ultrasonic cleaner partially filled with deionized water at 50 °C, and left for 30 min to enhance the structural properties of the solution. It is worth mentioning here, that the molarity of copper (0.6 M) was chosen based on a previous study [33].

Solution deposition using spin-coating technique

Si n-type substrate with an orientation of <100> was cleaned by immersing it in standard cleaning solutions (RCA 1 and RCA 2) successively to remove residual organic, ionic and metallic contamination as shown in Fig. S1a. Next, a layer of O_2 was etched on top of the Si substrate by exposing it to a temperature of 1000 °C for 1 h under a flow of O₂ gas using diffusion furnace (MODU-LAB, USA, http://www.modu-lab. com) as depicted in Fig. S1b. A few drops of the resulting solution were deposited, using plastic dropper, on the O₂/Si substrate. A spin coater (Laurell WS-400B, USA, http://www. laurell.com) was used at a rotation speed of 2500 RPM for 30 s to deposit the solution on the substrate, followed by drying the substrate at 80 °C for 1 min. The spin coating and drying processes were repeated 15 times to obtain a uniform nanostructure layer with a proper thickness at the top of O_2/Si substrate as shown in Fig. S1c. Subsequently, the substrate was annealed at 400 °C for 1 h under N₂ gas flow to keep the deposited nanostructure coherent, and then it was cooled to room temperature. This deposition process yielded a CCTS/O₂/Si sample. The annealing temperature of 400 °C was chosen based on a previous study [32].

Fabrication of ag interdigitated electrodes

For the deposition of effective interdigitated electrodes, a hard mask made from chrome was used since it is more favored than conventional lithography method due to its simplicity and the ease of application. Silver (Ag) was used for the deposition of interdigitated electrodes with a thickness of 200 nm on CCTS/O₂/Si using a thermal evaporator (PVD) vacuum coater which lead to the formation of a substrate with 4 layers; Ag/CCTS/O₂/Si as depicted in Fig. S1d. Moreover, Fig. S1e clearly shows the cross section view of the final sample. According to the specifications of the PVD machine, the thickness was proportional to the weight of raw silver used in the process hence, there is a direct correlation between weight and thickness. The thickness of IDE's was measured and displayed on the PVD indicator.

Immobilization and hybridization of dengue DNA

All DNA oligonucleotides of Dengue serotype-2 were purchased from Sigma-Aldrich. Totally, 7 different oligonucleotides were prepared, which included the capture DNA probe and 6 targets with different concentrations. The sequence of the capture DNA probe, modified with carboxylic group at 5'end, was 5'-COOH-ATGAAGCTGTAGTCTCACTGGAAGG-3'; the target sequence was 5'-CCTTCCAGTGAGACTACAGC TTCAT-3'. In this assay we used 4 Ag/CCTS/O₂/Si substrates. Firstly, 6 different concentrations were prepared from the specific target DNA sequence; 100 fM, 1 pM, 10 pM, 100 pM, 1 nM and 10 nM. The medium used to bind DNA molecules to the surface of the deposited CCTS nanostructures was (3-Aminopropyl)triethoxysilane (APTES), which was in very small quantities to covalently bond them. Secondly, a 100 µL of 49% deionized water, 49% Ethanol and 2% APTES was prepared and used as a primary solution followed by adding few drops from this solution onto the fingers of the electrodes. The sample was left covered and incubated for 1 h, then excess solution was sucked by pipetting followed by one wash with water. Finally, a manual dryer was used to dry the sample properly. Thirdly, 50% of EDC and 50% of NHS (100 µL total volume) were mixed together and then pipetted on the fingers of the electrodes. The sample was left intact for 10 min followed by sucking excess fluid, followed a quick wash with few drops of water and then drying. Fourthly, a few drops of the DNA probe were dropped on the fingers of the electrodes and the sample was left intact to incubate for 1 h followed by sucking excess DNA probe, washing with water, and then drying. Electrical properties of the DNA probe were identified after that. Dengue DNA concentrations similar to those above in step four (from 100 f. to 10 nM) were used but with an incubation period of 10 min. Electrical properties were evaluated for every concentration using Keithley 6487 and Alpha-A. It is worth mentioning, the resulted data have been generated in two forms; text and image files. The used voltage in the assay was from -3to 3 V whereas the used frequency was from 1 MHz to 1 Hz.

The optical properties of CCTS have been tested using UVvis spectrometer (Perkin Elmer Lambda 35, USA, http://www. perkinelmer.com). The reflection spectra were recorded over the wavelength range 200–1000 nm and the energy band gap has been identified. Also, the structural properties have been investigated via X-ray diffractometer (Bruker D2 PHASER, Germany, https://www.bruker.com), which record the intensity as a function of Bragg's angle in 2θ range from 10° - 60° using Cu k $\alpha(\lambda = 1.5406 \text{ Å})$. The major diffraction peaks have been recorded and attributed to the corresponding planes. The topography was characterized by Atomic Force Microscopy (AFM) (SPA 400, Seiko Instruments Inc., Japan, http://www.sii.co.jp/en) with a scanning area of 10 μ m × 10 µm and a scanning rate of 1 Hz, whereas, the surface morphology was investigated using Scanning Electron Microscopy (SEM) (JSM-6010LV, USA, http://www.jeolusa. com) with a magnification factor of ×2000. Electrical properties of DNA probe and the different concentrations of the Dengue DNA serptype-2 are characterized by using (Keithley 6487, Tektronix, USA, http://www.tek.com) and (Alpha-A High-performance Modular Measurement System, novocontrol, Germany, http://www.novocontrol.de).

Results and discussion

Choice of materials

The selection of the proper elements for making a quaternary alloy should be carefully considered. The high cost of indium and gallium obstructs further development of $CuIn_{1-x}Ga_xSe_2$ (CIGS). Also, Cu and Zn have similar ionic radii and this causes antisite defects in Cu_2ZnSnS_4 (CZTS). Not to mention the use of copper because of its high conductivity of electric charges, the expensive and scarce indium element was replaced with cadmium; gallium was replaced with Sn, and Se with the abundant and cheap S.

CCTS analysis and characterization

Optical properties

Reflectometry was performed at room temperature using UVvis spectroscopy at the range of 200–1000 nm to investigate the reflection spectra. According to Tauc formula for direct band gap semiconductors, the energy band gap of CCTS alloy nanostructures can be estimated using the following:

$$\left(\alpha h v\right)^2 = A\left(h v - E_g\right) \tag{1}$$

where α is the absorption coefficient, *A* is a constant, E_g is the energy band gap, *v* is incident photon frequency and *h* is the Planck's constant. The energy band gap is estimated from absorption spectra $(\alpha h v)^2$ versus *hv* by extrapolating the straight line portion of the curve to zero absorption coefficient as shown in Fig. S2. The energy band gap was found to be 1.35 eV, which was in good agreement with previous reports [26–33].

Structural properties

The CCTS alloy nanostructures were investigated by XRD as shown in Fig. S3. XRD pattern provided information about the crystalline structure of the nanoparticles as well as the crystallite size. After studying the patterns, four major diffraction peaks appeared at $2\theta = 28.7^{\circ}$, 29.57° , 47.77° and 55.95, which were attributed to 200, 112, 204 and 116 planes, respectively. All resulting peaks were matched with the tetragonal stannite structure of CCTS corresponding to the standard (ICDD PDF2008, 00-029-0537). It was noticed that the main peak was at 112 plane. The lattice constants a and c were calculated from XRD pattern of the 112 plane, using the eqs. (S1 to S7) listed in the electronic supplementary material according to the tetragonal crystal system. Also, Table S1 displays the values of a and c along with other structural parameters.

Topographical and morphological studies

The surface topography of CCTS was characterized. Fig. S4 shows 2-D and 3-D images with an area of 10 $\mu m \times 10 \ \mu m$ at 1 Hz scan rate. The measured roughness was 15.7 nm. The SEM image shown in Fig. S5 depicted the surface morphology of CCTS. A closer look at the image shows that the sample has a needle's shape.

Interdigitated electrodes characterization

Silver (Ag) fabricated IDEs were deposited on CCTS/O2/Si substrate using thermal evaporator that formed a pair of interdigitated electrodes with 4 fingers each. Ag was selected for fabricating electrodes because it has a very high electrical conductivity compared to other elements. The IDEs comprised 8 fingers which were 3.75 mm long (L), 0.25 mm wide (W) and 0.25 mm gap (G) between two adjacent interdigitated electrodes as shown in Fig. S6a. Moreover, the thickness of the fingers was 200 nm. Furthermore, the microscopic image captured by the polarizing microscope (Olympus BX51P, USA, http://www.olympus-ims.com) displayed part of IDEs and the scattered black spots confirmed the existence of CCTS alloy nanostructures as depicted in Fig. S6b. Lastly, an image of the whole sample with Ag IDEs is shown in Fig. S6c.

Electrical properties of the biosensor

Electrical properties at different Dengue DNA serotype-2 concentrations were investigated first using Keithley 6487 with twopoint probes. When applying voltage ranging from -3 to 3 V, the results indicated that the highest current was 4 µA at DNA probe followed by 100 fM, 1 pM, 10 pM, 100 pM, 1 nM and 10 nM concentrations. The current was lowest (1 µA) at 10 nM. As shown in Fig. 1a, a semi-linear relationship was identified as

Fig. 1 Electrical properties of а b Resistance (Ω) Current (A) 6.0E+6 4.5E-6 3.0E-6 4.0E+6 1.5E-6 0.0E+0 2.0E+6 1 2 3 1.5E-6 Voltage (V) 0.0E+0 -3.0E-6 -3 -2 0 -1 1 2 3 -4.5E-6 Voltage (V) DNA Probe 10 nM DNA Probe 10 nm Ma 01-1 nM -100 pm nm 100 fM 10pm 1pm Ma 1 -100 pM 100 fm d С Power (W) Conductance (S) 1.5E-5 1.5E-6 1.0E-5 0E-6 5.0E-7 5.0E-6 0.0E+0 0.01 -3 -3 -2 -1 0 1 2 3 -2 -1 0 1 2 3 Voltage (V) Voltage (V) DNA Probe 10 nM 10 nM DNA Probe 1 nM 10 pM 1 nM Ma 01 100 fM 100 fM 1 pM •1 pM – 100 pM 100 pM

biosensor at different Dengue DNA concentrations using Keithley 6487, (a) current versus voltage. (b) resistance versus voltage, (c) conductance versus voltage and (d) power versus voltage

Schottky barrier formed at a metal-semiconductor junction. IDEs have metallic electrodes on Si substrate, with a thin insulator of O₂, therefore, the I-V curves showed finite currents at zero voltage. This was caused by the charging effect on the electrical double layer capacitance and the existence of the quaternary alloy between the O2 layer and IDEs. It worth mentioning here that an inverse relationship exists between concentration and current. Ibraheam et al. [34] have reported Dengue DNA type 2 biosensor based Cu₂Zn_{1-x}Cd_xSnS₄ quinternary alloy nanostructures. Dielectric measurements of current to voltage (I–V) were taken with recorded readings from -6 V to 6 V, the results indicated that the highest was at DNA probe followed by 100 fM, 1 pM, 10 pM, 100 pM, 1 nM and 10 nM which is in agreement with this research. As depicted in Fig. 1b, the highest resistance was 5 M Ω at 10 nM followed by 1 nM, 100 pM, 10 pM, 1 pM, 100 f. and DNA probe. The resistance was 1 M Ω at DNA probe. Of these figures, decreasing the concentration will lead to decreasing the resistance and vise-versa. These results were consistent with the results of the I-V test. It was noticed that applying zero voltage will force the resistance to drop to zero for all concentrations. Interestingly, when the gap between two adjacent interdigitated electrodes increased, the resistance also increased. This was due to charge carriers having to travel a larger distance. As illustrated in Fig. 1c, the highest conductance was 1.2 µS at DNA probe followed by 100 fM, 1 pM, 10 pM, 100 pM, 1 nM and 10 nM, whereas 10 nM being the lowest (0.4

Fig. 2 Electrical properties of biosensor at different Dengue DNA concentrations using Alpha-A analyzer, (**a**) capacitance versus frequency, (**b**) impedance versus frequency and (**c**) conductivity versus frequency. The insets in a and b show the frequency trends in the first 100 Hz μ S). Collectively, our results corroborated the R-V test and the inverse relationship between the resistance and conductance. Electrical power is the rate at which electrical energy is transferred by an electric circuit and it is measured in watt (W), one joule per second, and it results from multiplying voltage (V) by current (I). As shown in Fig. 1d, the highest power of 11 μ W was obtained at the DNA probe followed by 100 fM, 1 pM, 10 pM, 100 pM, 1 nM and 10 nM- power was lowest (3 μ W) at 10 nM. These results are consistent with the results of the I-V test in that the current has a proportional relationship with the power.

The second set of measurements were implemented by Alpha-A to investigate a different group of electrical parameters as a function of frequency. The capacitance increases with decreasing the frequency in an inverse relationship, as shown in Fig. 2a, the capacitance for most concentrations started from 0.0009 µF at 1 MHz and continued to increase as frequency decreased until it reached 1 Hz. As shown in the internal inset of Fig. 2a, the highest capacitance was 0.04 µF at DNA probe followed by 100 fM, 1 pM, 100 pM, 10 pM, 1 nM and 10 nM. The capacitance was 0.0075 µF at 10 nM. Despite the current findings, capacitance can be increased by increasing the number of fingers as well as increasing the thickness of the electrodes. On the other hand, electrical impedance is a measure of the opposition by a circuit to a current when the voltage is applied. Impedance possesses both magnitude and phase, unlike resistance, which has only magnitude. Fig. 2b shows the impedance



at different Dengue DNA serotype-2 concentrations as a function of frequency. The impedance for most concentrations started from 0.17 K Ω at 1 MHz and continued to increase as frequency decreased until it reached 1 Hz. As shown in the internal inset of Fig. 2b, the highest impedance was 5.25 M Ω at 10 nM followed by 1 nM, 10 pM, 100 pM, 1 pM, 100 f. and DNA probe. The impedance was 1 M Ω in DNA probe. Moreover, impedance increases as frequency decreases, and our results corroborate this; whereas 10 nM DNA concentration was the highest in the impedance test it yielded the lowest outcome in the capacitance test. The conductivity for most concentrations started from 2.5 µS/m at 1 MHz and continued to decrease as frequency decreased until it reached 1 Hz except for the DNA probe, which started from 0.55 µS/m. As shown in Fig. 2c, there is a significant overlap between the different concentrations, and most of them have almost the same amount of conductivity except DNA probe which has a lower conductivity than the others.

Fig. S7a displays the permittivity of the different concentrations of Dengue DNA serotype-2 as a function of frequency. The permittivity for most of the concentrations started from 8 F/m at 1 MHz and continued to increase with decreasing frequency until reaching 1 Hz. As shown in the internal inset of Fig. S7a, the highest permittivity was 1400 F/m at DNA probe followed by 100 fM, 1 pM, 10 pM, 100 pM, 1 nM and 10 nM. The permittivity was 270 F/m at 10 nM. On the other hand, Fig. S7b shows the modulus for different concentrations of Dengue DNA serotype-2 as a function of frequency. The modulus for most of the concentrations started from 0.12 m/F at 1 MHz and continued to increase with the decrease of the frequency up to 1 Hz. There was a great amount of overlapping between the different concentrations albeit the same amount of modulus.

The third set of measurements were recorded using Alpha-A High to find capacitance and impedance as a function of voltage. Fig. 3a shows the capacitance at different concentrations of Dengue DNA serotype-2 as a function of voltage; most of the concentrations fluctuated between 0.001 μ F and 0.0025 μ F. It is worth mentioning, there is a slight increase in capacitance as voltage increases. Moreover, the highest capacitance was obtained at DNA probe followed by 1 pM, 100 fm, 10 pM, 100 pM, 1 nM and 10 nM. Finally, Fig. 3b shows the impedance at different concentrations of Dengue DNA serotype-2 as a function of voltage; most of the concentrations fluctuated between 0.4 M Ω and 1.4 M Ω . There was a slight decrease in impedance as voltage increased. Moreover, the highest impedance was at 10 nM followed by 1 nM, 10 pM, 100 pM, 100 fM, 1 pM and DNA probe.

Performance of the biosensor

The development of analytical method is always evaluated in terms of performance and effectiveness. In this study, sensitivity, limit of detection (LOD) and limit of quantification (LOQ) are important factors in method validation. The sensitivity can be evaluated by measuring the slope of the resulting current versus DNA concentration. Sensitivity of the biosensor is calculated using the following equation;

$$Sensitivity = \frac{slope \ of \ calibration \ plot \ (\mu A \ nM^{-1})}{active \ surface \ area \ (cm^2)}$$
(2)

There are 3 common methods for the estimation of detection and quantitation limit; Visual definition, calculation from the signal-to-noise ratio and calculation from the standard deviation of the concentrations, which was used in the current study. The calibration equation was established as a function of DNA concentration; $y = -0.0604 \times + 1.0167$ where y is the transduced current and x is DNA concentration. As shown in Fig. 4, the linear regression, $R^2 = 0.5059$ and the slope m = 0.0604 µA nM⁻¹ were also calculated. The calculated sensitivity of the biosensor was 24.2 μ A nM⁻¹ cm⁻² which is considered as a high sensitivity. The standard deviation of the current was $0.34 \ \mu A$ and the calculated LOD of the biosensor was 16.9 nM, and accordingly, the calculated LOQ of the biosensor was 56.3 nM. To compare with the present biosensor, various types of DNA biosensors have been reported. Nuzaihan et al. [35] have achieved Dengue virus DNA detection using silicon nanowire biosensor by molecular gate control which demonstrated the device sensitivity of 45 μ A nM⁻¹ cm⁻².

Fig. 3 Electrical properties of biosensor at different Dengue DNA concentrations using Alpha-A analyzer, (**a**) capacitance versus voltage and (**b**) impedance versus voltage





Fig. 4 Sensitivity of the biosensor. Current (μ A) versus DNA concentration (nM). The acquired results are obtained at 1.5 V

Conclusions

CCTS alloy nanostructures were successfully synthesized and deposited on O2/Si substrate via spin coating technique at an annealing temperature of 400 °C. UV-vis measurement demonstrated that energy band gap was 1.35 eV. XRD patterns revealed the presence of four peaks; the highest corresponded to (112) plane whereas, crystallite size was 20.4 nm. The morphological and topographical studies indicated the presence of a needle's shape, whereas the measured roughness was 15.7 nm. Ag interdigitated electrodes were fabricated on CCTS/O2/Si using a hard mask and thermal evaporator. There was a clear difference between the different concentrations of DNA used in all tests. The current study revealed a proportional relationship with the voltage which is explained as Schottky barrier hence. On the other hand, capacitance and impedance displayed an inverse relationship, whereas, they are affected slightly by changing the voltage. Moreover, Conductivity increased with increasing frequency. It is worth mentioning here, longitudinal design parameters, such as the spacing between fingers, fingers width and fingers thickness are very important factors when designing biosensors. The calculated sensitivity of the biosensor was 24.2 μ A nM⁻¹ cm⁻², whereas the calculated LOD and LOO were 16.9 and 56.3 nM, respectively. Overall, we have designed, fabricated and characterized a small and low-cost sensor that has a high sensitivity as well as an adequate LOD and LOQ. The results showed that the fabricated biosensor is promising for detecting the Dengue DNA serotype-2.

Compliance with ethical standards The author(s) declare that they have no competing interests.

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